



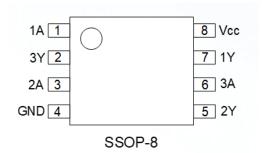
Description

The DIODES™ 74LVC3G34 is a triple buffer gate with standard pushpull outputs. The device is designed for operation with a power supply range of 1.65V to 5.5V. The inputs are tolerant to 5.5V allowing this device to be used in a mixed voltage environment. The device is fully specified for partial power down applications using I_{OFF}. The I_{OFF} circuitry disables the output preventing damaging current backflow when the device is powered down.

Each of the buffers performs the positive Boolean function:

Y = A

Pin Assignments



Features

- Wide Supply Voltage Range from 1.65V to 5.5V
- ±24mA Output Drive at 3.3V
- CMOS Low Power Consumption
- Ioff Supports Partial-Power-Down Mode Operation
- Inputs Accept up to 5.5V
- ESD Protection Tested per JESD 22
 Exceeds 2,000V Human Body Model (A114)
 Exceeds 1,000V Charged Device Model (C101)
- Latch-Up Exceeds 100mA per JESD 78, Class I
- Range of Package Options
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

Applications

- · Voltage level shifting
- · General purpose logic
- · Power down signal isolation
- · Wide array of products such as:
 - · PCs, networking, notebooks, netbooks, PDAs
 - · Computer peripherals, hard drives, CD/DVD ROM
 - · TV, DVD, DVR, set top boxes
 - Cell phones, personal navigation / GPS
 - MP3 players, cameras, video recorders

Notes:

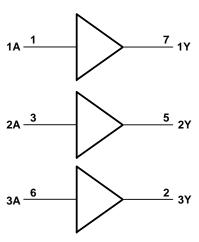
- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.



Pin Descriptions

Pin Name	Pin NO.	Description
1A	1	Data Input
3Y	2	Data Output
2A	3	Data Input
GND	4	Ground
2Y	5	Data Output
3A	6	Data Input
1Y	7	Data Output
Vcc	8	Supply Voltage

Logic Diagram



Function Table

Inputs	Output
Α	Y
Н	Н
L	L

Absolute Maximum Ratings (Notes 4, 5)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	kV
ESD CDM	Charged Device Model ESD Protection	1	kV
Vcc	Supply Voltage Range	-0.5 to 6.5	V
VI	Input Voltage Range	-0.5 to 6.5	V
Vo	Voltage Applied to Output in High Impedance or IOFF State	-0.5 to 6.5	V
Vo	Voltage Applied to Output in High or Low State	-0.5 to V _{CC} +0.5	V
l _{IK}	Input Clamp Current V _I < 0	-50	mA
lok	Output Clamp Current Vo < 0	-50	mA
lo	Continuous Output Current	±50	mA
Icc, Ignd	Continuous Current Through V _{CC} or GND	±100	mA
TJ	Junction Temperature	+150	°C
T _{STG}	Storage Temperature	-65 to +150	°C

Notes:

- 4. Stresses beyond the absolute maximum can result in immediate failure or reduced reliability. These are stress values and device operation should be
- within recommended values.

 5. Forcing the maximum allowed voltage could cause a condition exceeding the maximum current or conversely forcing the maximum current could cause a condition exceeding the maximum voltage. The ratings of both current and voltage must be maintained within the controlled range.



Recommended Operating Conditions (Note 6)

Symbol	Parameter	Conditions	Min	Max	Unit	
\/	Operating Voltage	Operating	1.65	5.5	V	
Vcc	Operating voltage	Data Retention Only	1.5	_	V	
		Vcc = 1.65V to 1.95V	0.65 X Vcc	_		
\ /	High Loyal Input Valtage	Vcc = 2.3V to 2.7V	1.7	_	V	
ViH	High-Level Input Voltage	Vcc = 3V to 3.6V	2	_	V	
		Vcc = 4.5V to 5.5V	0.7 X Vcc	_		
		V _{CC} = 1.65V to 1.95V	_	0.35 X V _{CC}		
.,	Law Law Law Waltage	Vcc = 2.3V to 2.7V	_	0.7	.,	
V _{IL}	Low-Level Input Voltage	Vcc = 3V to 3.6V	_	0.8	V	
		V _{CC} = 4.5V to 5.5V	_	0.3 X V _{CC}		
Vı	Input Voltage	_	0	5.5	V	
Vo	Output Voltage	_	0	Vcc	V	
		Vcc = 1.65V	_	-4		
		Vcc = 2.3V	_	-8		
Іон	High-Level Output Current	Vcc = 3V	_	-16	mA	
	VCC	VCC = 3V	_	-24		
		Vcc = 4.5V	_	-32		
		Vcc = 1.65V	_	4		
		V _{CC} = 2.3V	_	8		
I _{OL}	Low-Level Output Current	Vcc = 3V	_	16	mA	
		VCC = 3V	_	24	1	
		Vcc = 4.5V	_	32		
		$V_{CC} = 1.8V \pm 0.15V, 2.5V \pm 0.2V$	_	20		
Δt/ΔV	Input Transition Rise or Fall Rate	Vcc = 1.65V to 2.7V	_	10	ns/V	
		Vcc = 2.7V to 5V	_	5		
TA	Operating Free-Air Temperature	_	-40	+125	°C	

Note: 6. Unused inputs should be held at V_{CC} or Ground for device proper operation.



Electrical Characteristics

Cumbal	Davamatar	T(O	.,	-40°C to	+85°C	-40°C to	+125ºC	_
Symbol	Parameter	Test Conditions	V _{CC}	Min	Max	Min	Max	Unit
		$I_{OH} = -100 \mu A$	1.65V to 5.5V	V _{CC} – 0.1	_	V _{CC} – 0.1	_	
		IoH = -4mA	1.65V	1.2	_	1.2	_	
Mari	High Level Output Voltage	I _{OH} = -8mA	2.3V	1.9	1	1.9	1	V
Vон	Trigit Level Output voltage	Iон = -16mA	3V	2.4	_	2.4	_	V
		Iон = -24mA	3 V	2.3	_	2.3	_	
		Iон = -32mA	4.5V	3.8	_	3.8	_	
		I _{OL} = 100μA	1.65V to 5.5V	_	0.1	_	0.1	- V
		IoL = 4mA	1.65V	_	0.45	-	0.45	
Mai		I _{OL} = 8mA	2.3V	_	0.3	-	0.3	
Vol	Low Level Output Voltage	IoL = 16mA	- 3V	_	0.4	_	0.4	V
		I _{OL} = 24mA		_	0.55	-	0.75	
		I _{OL} = 32mA	4.5V	_	0.55	-	0.75	
lı	Input Current	V _I = 5.5V or GND	0 to 5.5V	_	±5	1	±5	μA
loff	Power Down Leakage Current	V _I or V _O = 5.5V	0	_	±10	-	±10	μA
Icc	Supply Current	V _I = 5.5V or GND, Io = 0	1.65V to 5.5V	_	10	_	10	μA
Δlcc	Additional Supply Current	Input at V _{CC} - 0.6V	3V to 5.5V	_	500	_	500	μA
Cı	Input Capacitance	V _I = V _{CC} or GND	3.3V	_	3.5 (Typ)	_	_	pF

Package Characteristics

Symbol	Parameter	Package	Test Conditions	Min	Тур	Max	Unit
Θ_{JA}	Thermal Resistance Junction-to-Ambient	SSOP-8	Note 7	_	130	_	°C/W
Өлс	Thermal Resistance Junction-to-Case	SSOP-8	Note 7	-	36	_	°C/W

Note: 7. Test condition for SSOP-8: Device mounted on JEDEC 2s2p High-K board, FR-4 substrate PCB, 2oz copper with minimum recommended pad layout.

Operating Characteristics (TA = +25°C, VCC = 3.3V)

Symbol	Parameter	Test Conditions	Vcc = 1.8V Typ	Vcc = 2.5V Typ	Vcc = 3.3V Typ	Vcc = 5V Typ	Unit
CPD	Power Dissipation Capacitance	f = 10MHz, 1 Input Switching	19	19	19	21	pF

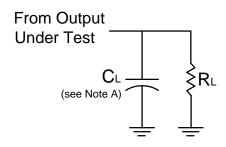


Switching Characteristics

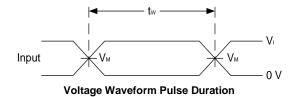
Figure 1

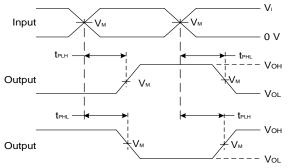
Parameter	From To		V	T _A = -40°C	T _A = -40°C to +85°C		T _A = -40°C to +125°C	
Parameter	Input	Output	Vcc	Min	Max	Min	Max	Unit
	A Y		1.8V ± 0.15V	3.2	7.9	3.2	8.9	
4		V	$2.5V \pm 0.2V$	1.5	4.4	1.5	5.4	
tpD		$3.3V \pm 0.3V$	1.4	4.1	1.4	5.1	ns	
	ţ	5.0V ± 0.5V	1.1	3.2	1.1	3.8		

Parameter Measurement Information (Notes B, C, D)



Vcc	Inputs		. V _M	CL	RL	
***************************************	Vı	t _r /t _f	V M	OL.	ΝL	
1.8V ± 0.15V	Vcc	≤2ns	Vcc/2	30pF	1kΩ	
2.5V ± 0.2V	Vcc	≤2ns	Vcc/2	30pF	500Ω	
$3.3V \pm 0.3V$	3V	≤2.5ns	1.5V	50pF	500Ω	
5.0V ± 0.5V	Vcc	≤2.5ns	V _{CC} /2	50pF	500Ω	





Voltage Waveform Propagation Delay Time Inverting and Non Inverting Outputs

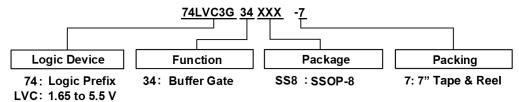
Figure 1 Load Circuit and Voltage Waveforms

Notes: A. Includes test lead and test apparatus capacitance.

- B. All pulses are supplied at pulse repetition rate ≤ 10MHz.
- C. Inputs are measured separately one transition per measurement.
- D. t_{PLH} and t_{PHL} are the same as t_{PD} .



Ordering Information



Family 3G: Triple Gate

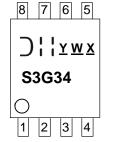
5 (1)			Pac	king
Part Number	Package Code	Package	Qty.	Carrier
74LVC3G34SS8-7	SS8	SSOP-8	3,000	7" Tape and Reel (Note 8)

8. The taping orientation is located on our website at http://www.diodes.com/package-outlines.html. Note:

Marking Information

SSOP-8

(Top View)



52 and 53 week X: Internal Code

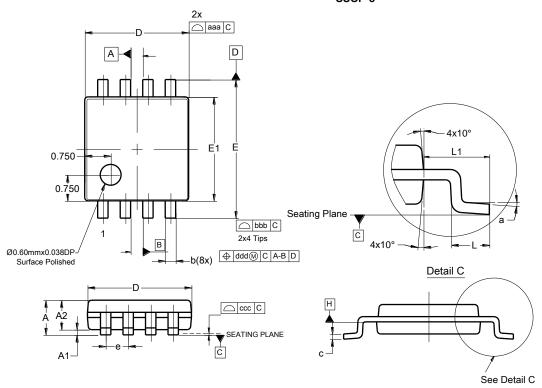
Part Number	Package	Identification Code
74LVC3G34SS8-7	SSOP-8	S3G34



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SSOP-8

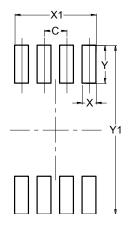


	SS	OP-8			
Dim	Min	Max	Тур		
Α		1.30			
A1	0.05	0.15			
A2	0.95	1.20	1.05		
b	0.15	0.30	0.225		
С	0.08	0.23	-		
D	2.75	3.15	2.95		
Е	3.75	4.25	4.00		
E1	2.70	2.90	2.80		
е		1	0.65		
L	0.20	0.60	0.40		
L1	0.525	0.675	0.60		
а	0°	8°	4°		
aaa	0.20				
bbb	0.25				
CCC	0.10				
ddd	0.13				
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SSOP-8



Dimensions	Value
	(in mm)
С	0.650
Χ	0.400
X1	2.350
Y	1.100
Y1	4.900

Mechanical Data

SSOP-8

- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Mate Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.0169 grams (Approximate)



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